# High Power Laser Diode C-mount



# Part Number: C-123

High Power C-mount Single-Mode Fabry-Perot CW Wavelength at 1625nm Lensed Options Available

### Features

- High Output Power
- High Dynamic Range
- High Efficiency
- Standard C-mount
- Cost Effective

# Application

- Laser Range Finder
- Target Illumination





SemiNex delivers the highest available power at infrared wavelengths between 12xx and 19xx nm. When necessary, we will further optimize the design of our InP & GaSb laser chips to meet our customers' specific optical and electrical performance needs. Diodes, bars and packages are tested to meet customer and market performance demands. Typical results and packaging options are shown. Contact SemiNex for additional details or to discuss your specific requirements.



## Specification

C-123



Optical	Symbol	Тур.	Units
Center Wavelength	λ <sub>c</sub>	1625	nm (±20)
Output Power (CW)*	Pout	0.4	watts (±10%)
Emitter Width	W	4	μm
Spectral Width FWHM	Δλ	15	nm
Slope Efficiency	η	0.3	W/A
Fast Axis Div.	Θ⊥	30	deg FWHM
Slow Axis Div.	Θ <sub>ll</sub>	10	deg FWHM
Electrical	Symbol		Units
Power Conversion Eff.	η	11	%
Threshold Current			
	Ітн	0.05	A
Operating Current	ITH I <sub>op</sub>	0.05	A
Operating Current	l <sub>op</sub>	1.6	A
Operating Current Operating Voltage	l <sub>op</sub> V <sub>op</sub>	1.6 3.1	A V

\*Specified values are rated at a constant heat sink temperature of 20°C. \*\*High temperature operation will reduce performance and MTTF. Unless otherwise indicated all values are nominal.

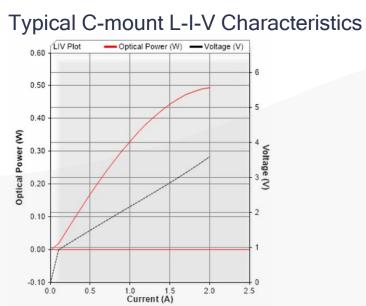
#### \*Available Lenses

Suffix	Description
-118	Lens Collimated <10mrad f=274µm, 5mm Lg
-134	Lens Matched f=274µm, 5mm Lg
-141	Lens, FAC, f=590µm, 5mm Lg, Collimated 5mrad
-186	Lens, FAC, f=590µm, 5mm Lg, WD=50µm

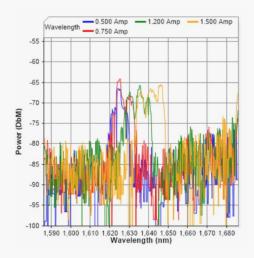
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#### SemiNex Laser Diodes C-123

#### Graphs & Data



#### Typical C-mount Output Spectrum





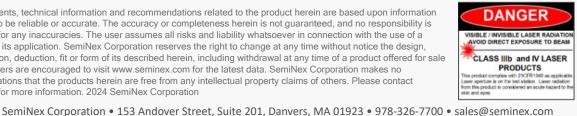


## **High Power Laser Diode** C-mount

**Mechanical Drawing** 

1.52 4.30 -WIRE BONDS COUNT VARIES BASED ON CAVITY LENGTH ł 0.20 FLYING LEAD CATHODE (-) LASER DIE Ø 2.29 THRU ALL \_\_\_\_ Ø 4.45 ∓ 2.30 0.20 -L. INSULATING BLOCK 7.52 BODY ANODE[+] 2.79 - 3.18 -

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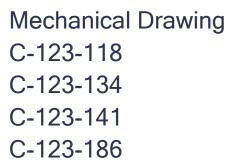
DANGER

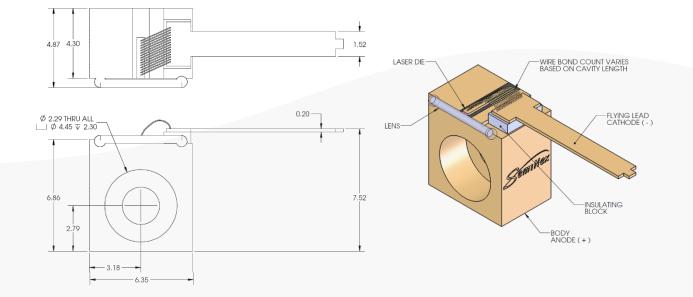
ISIBLE / INVISIBLE LASER RADIATIO

CLASS IIIb and IV LASER

PRODUCTS

## High Power Laser Diode C-mount





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